

# Low Noise Amplifier with Bypass for 5 GHz band

#### ■ FEATURES

- Wide frequency range 4900MHz to 5950MHz
- Low operating voltage 1.5V to 3.3 V
- Low current 5.0/3.5mA typ. @ V<sub>DD</sub>=2.8/1.8V
  High gain
- 15.0dB typ. @ V<sub>DD</sub>=2.8V, f<sub>RF</sub>=5500 MHz • Low noise figure
  - 1.1dB typ. @ V<sub>DD</sub>=2.8V, f<sub>RF</sub>=5500MHz
- High IIP3
- +2.0dBm typ.@V<sub>DD</sub>=2.8V,f<sub>RF</sub>=5500MHz+5501MHz • Low insertion loss (bypass mode)
- 3.5dB typ.@ V<sub>DD</sub>=2.8V, f<sub>RF</sub>=5500MHz
- Ultra-small package size 1.1 x 0.7 x 0.37mm typ.
- RoHS compliant and Halogen Free, MSL1

### ■ GENERAL DESCRIPTION

NJG1182UX2 is low noise amplifier with bypass switch for 5GHz application such as LTE-U/LAA, which covers frequency from 4900MHz to 5950MHz.

NJG1182UX2 is able to select LNA active mode or bypass mode by low control voltage. This LNA achieves low noise figure and high linearity.

Integrated ESD protection device on each port achieves excellent ESD robustness.

A very small and ultra-thin package EPFFP6-X2 is adopted.

### TRUTH TABLE

#### "H"=VCTL(H), "L"=VCTL(L)

| VCTL | Mode            |
|------|-----------------|
| Н    | LNA active mode |
| L    | Bypass mode     |

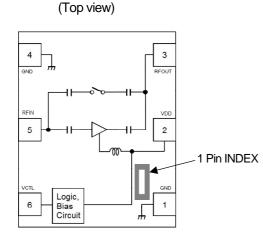
#### PIN CONFIGURATION

| PIN NO. | SYMBOL | DESCRIPTION     |
|---------|--------|-----------------|
| 1       | GND    | Ground          |
| 2       | VDD    | Power supply    |
| 3       | RFOUT  | RF output       |
| 4       | GND    | Ground          |
| 5       | RFIN   | RF input        |
| 6       | VCTL   | Control voltage |

# 

- LTE-U/LAA receive application
- WiMAX 5GHz receive application
- WLAN 5GHz receive application
- RF front-end modules, data cards, and other mobile applications

#### BLOCK DIAGRAM (EPFFP6-X2)



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#### PRODUCT NAME INFORMATION

NJG1182 UX2 (TE1) | | | Part number Package Taping form

# ORDERING INFORMATION

| PART NUMBER | PACKAGE<br>OUTLINE | RoHS | HALOGEN-<br>FREE | TERMINAL<br>FINISH | MARKING | WEIGHT<br>(mg) | MOQ (pcs.) |
|-------------|--------------------|------|------------------|--------------------|---------|----------------|------------|
| NJG1182UX2  | EPFFP6-X2          | Yes  | Yes              | Ni/Pd/Au           | 5       | 0.7            | 5,000      |

#### ■ ABSOLUTE MAXIMUM RATINGS

|                       |                  | T <sub>a</sub> = 25°C, Z | $G_{\rm s} = Z_{\rm l} = 50 \ \Omega$ |
|-----------------------|------------------|--------------------------|---------------------------------------|
| PARAMETER             | SYMBOL           | RATINGS                  | UNIT                                  |
| Operating voltage     | V <sub>DD</sub>  | 5.0                      | V                                     |
| Control voltage       | V <sub>CTL</sub> | 5.0                      | V                                     |
| Input power           | PIN              | +15 <sup>(1)</sup>       | dBm                                   |
| Power dissipation     | PD               | 430 <sup>(2)</sup>       | mW                                    |
| Operating temperature | T <sub>opr</sub> | -40 to +105              | °C                                    |
| Storage temperature   | T <sub>stg</sub> | -55 to +150              | ٥°C                                   |

(1): V<sub>DD</sub>=2.8V

(2): 4-layer FR4 PCB with through-hole (101.5x114.5mm), Tj=150°C

# ■ ELECTRICAL CHARACTERISTICS 1 (DC)

|                        |                     | General conditio                  | n: Ta=+2 | 5°C, with | applicati | on circuit |
|------------------------|---------------------|-----------------------------------|----------|-----------|-----------|------------|
| PARAMETER              | SYMBOL              | TEST CONDITION                    | MIN.     | TYP.      | MAX.      | UNIT       |
| Operating voltage      | Vdd                 |                                   | 1.5      | -         | 3.3       | V          |
| Control voltage (High) | Vctl(H)             |                                   | 1.3      | 1.8       | 3.3       | V          |
| Control voltage (Low)  | V <sub>CTL(L)</sub> |                                   | 0        | 0         | 0.3       | V          |
| Operating current 1    | I <sub>DD</sub> 1   | RF OFF,<br>Vdd=2.8V, Vctl=1.8V    | -        | 5.0       | 8.0       | mA         |
| Operating current 2    | I <sub>DD</sub> 2   | RF OFF,<br>Vdd=1.8V, Vcт=1.8V     | -        | 3.5       | 8.0       | mA         |
| Operating current 3    | IDD3                | RF OFF,<br>Vdd=2.8V, Vctl=0V      | -        | 20        | 60        | μΑ         |
| Operating current 4    | I <sub>DD</sub> 4   | RF OFF,<br>Vdd=1.8V, Vctl=0V      | -        | 10        | 60        | μΑ         |
| Control current        | Іст∟                | RF OFF,<br>V <sub>CTL</sub> =1.8V | -        | 7         | 20        | μA         |

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# ■ELECTRICAL CHARACTERISTICS 2 (LNA active mode)

General condition:  $V_{DD}=2.8V$ ,  $V_{CTL}=1.8V$ ,  $f_{RF}=5500MHz$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit

| PARAMETER   | SYMBOL            | TEST CONDITION   | MIN.  | TYP.  | MAX. | UNIT |
|---|-------------------|--|-------|-------|------|------|
| Small signal gain1                                  | Gain1             | Exclude PCB & connector losses *1  | 12.0  | 15.0  | 17.5 | dB   |
| Noise figure1                                       | NF1               | Exclude PCB & connector losses *2  | -     | 1.1   | 1.7  | dB   |
| Input power at 1dB<br>gain compression<br>point1(1) | P-1dB(IN)<br>1(1) |  | -16.0 | -11.0 | -    | dBm  |
| Input 3rd order<br>intercept point1(1)              | IIP3_1(1)         | f1=f <sub>RF</sub> , f2= f <sub>RF</sub> +1MHz,<br>P <sub>IN</sub> =-30dBm | -5.0  | +2.0  | -    | dBm  |
| RF IN<br>return loss1(1)                            | RLi1(1)           |  | 8.0   | 16.0  | -    | dB   |
| RF OUT<br>return loss1(1)                           | RLo1(1)           |  | 5.0   | 8.0   | -    | dB   |
| Gain settling<br>time1(1)                           | Ts1(1)            | Bypass to LNA active mode to be within 1 dB of the final gain              | -     | 1.0   | 2.5  | μs   |
| Gain settling<br>time1(2)                           | Ts1(2)            | LNA active to Bypass mode to be within 1 dB of the final insertion loss    | -     | 0.8   | 2.5  | μs   |

\*1: PCB and connector losses: 0.64 dB

\*2: PCB and connector losses: 0.30 dB

#### ■ ELECTRICAL CHARACTERISTICS 3 (Bypass mode)

General condition: VDD=2.8V, VCTL=0V, fRF=5500MHz, Ta=+25°C, Zs=ZI=50Q, with application circuit

| PARAMETER                                      | SYMBOL            | TEST CONDITION  | MIN.  | TYP.  | MAX. | UNIT |
|--|-------------------|---|-------|-------|------|------|
| Insertion Loss1                                | Loss1             | Exclude PCB & connector losses *1   | -     | 3.5   | 5.0  | dB   |
| Input power at 1dB<br>compression<br>point1(2) | P-1dB(IN)<br>1(2) |   | +2.0  | +7.5  | -    | dBm  |
| Input 3rd order<br>intercept point1(2)         | IIP3_1(2)         | f1=f <sub>RF</sub> , f2=f <sub>RF</sub> +1MHz,<br>P <sub>IN</sub> =-10dBm | +10.0 | +18.0 | -    | dBm  |
| RF IN<br>return loss1(2)                       | RLi1(2)           |   | 6.0   | 13.0  | -    | dB   |
| RF OUT<br>return loss1(2)                      | RLo1(2)           |   | 4.0   | 6.0   | -    | dB   |

\*1: PCB and connector losses: 0.64 dB

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# ■ ELECTRICAL CHARACTERISTICS 4 (LNA active mode)

General condition: V<sub>DD</sub>=1.8V, V<sub>CTL</sub>=1.8V, f<sub>RF</sub>=5500MHz, T<sub>a</sub>=+25°C, Z<sub>s</sub>=Z<sub>I</sub>=50Ω, with application circuit

| PARAMETER   | SYMBOL            | TEST CONDITION   | MIN. | TYP.  | MAX. | UNIT |
|---|-------------------|--|------|-------|------|------|
| Small signal gain2                                  | Gain2             | Exclude PCB & connector losses *1  | -    | 14.5  | -    | dB   |
| Noise figure2                                       | NF2               | Exclude PCB & connector losses *2  | -    | 1.4   | -    | dB   |
| Input power at 1dB<br>gain compression<br>point2(1) | P-1dB(IN)<br>2(1) |  |      | -13.0 |      | dBm  |
| Input 3rd order<br>intercept point2(1)              | IIP3_2(1)         | f1=f <sub>RF</sub> , f2= f <sub>RF</sub> +1MHz,<br>P <sub>IN</sub> =-30dBm | -    | -1.0  | -    | dBm  |
| RF IN<br>return loss2(1)                            | RLi2(1)           |  | -    | 11.0  | -    | dB   |
| RF OUT<br>return loss2(1)                           | RLo2(1)           |  | -    | 8.0   | -    | dB   |
| Gain settling<br>time2(1)                           | Ts2(1)            | Bypass to LNA active mode<br>To be within 1 dB of the final gain           | -    | 2.0   | -    | μs   |
| Gain settling<br>time2(2)                           | Ts2(2)            | LNA active to Bypass mode<br>To be within 1 dB of the final insertion loss | -    | 0.8   | -    | μs   |

\*1: PCB and connector losses: 0.64 dB

\*2: PCB and connector losses: 0.30 dB

#### ■ ELECTRICAL CHARACTERISTICS 5 (Bypass mode)

General condition: V<sub>DD</sub>=1.8V, V<sub>CTL</sub>=0V, f<sub>RF</sub>=5500MHz, T<sub>a</sub>=+25°C, Z<sub>s</sub>=Z<sub>I</sub>=50Ω, with application circuit

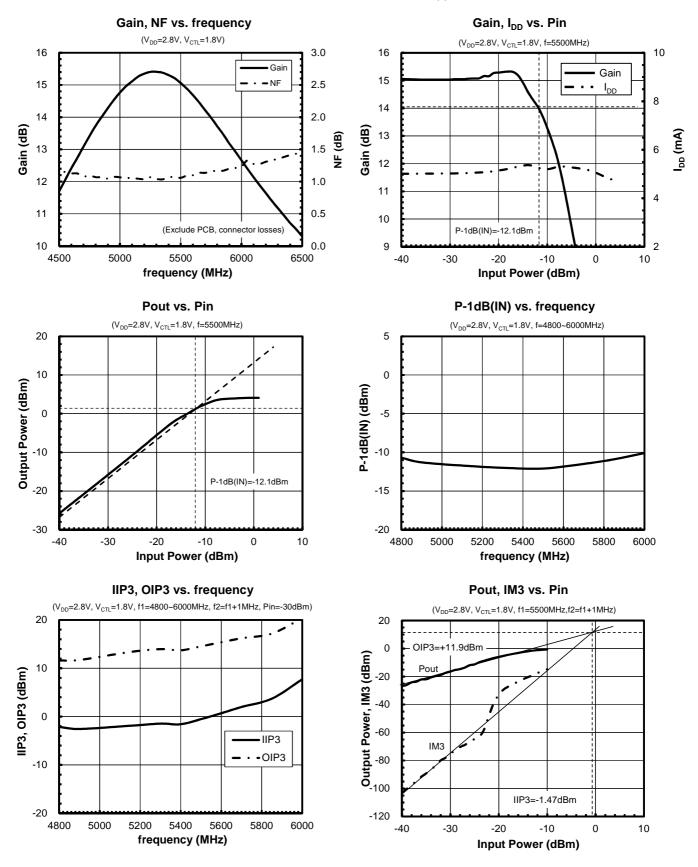
| PARAMETER                                      | SYMBOL            | TEST CONDITION  | MIN. | TYP.  | MAX. | UNIT |
|--|-------------------|---|------|-------|------|------|
| Insertion Loss2                                | Loss2             | Exclude PCB & connector losses *1   | -    | 3.5   | -    | dB   |
| Input power at 1dB<br>compression<br>point2(2) | P-1dB(IN)<br>2(2) |   | -    | +7.0  | -    | dBm  |
| Input 3rd order<br>_intercept point2(2)        | IIP3_2(2)         | f1=f <sub>RF</sub> , f2=f <sub>RF</sub> +1MHz,<br>P <sub>IN</sub> =-10dBm | -    | +18.0 | -    | dBm  |
| RF IN<br>return loss2(2)                       | RLi2(2)           |   | -    | 13.0  | -    | dB   |
| RF OUT<br>return loss2(2)                      | RLo2(2)           |   | -    | 7.0   | -    | dB   |

\*1: PCB and connector losses: 0.64 dB

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# ■ ELECTRICAL CHARACTERISTICS (LNA active mode)

Conditions: V<sub>DD</sub>=2.8V, V<sub>CTL</sub>=1.8V, f<sub>RF</sub>=5500MHz, T<sub>a</sub>=+25°C, Z<sub>s</sub>=Z<sub>I</sub>=50Ω, with application circuit

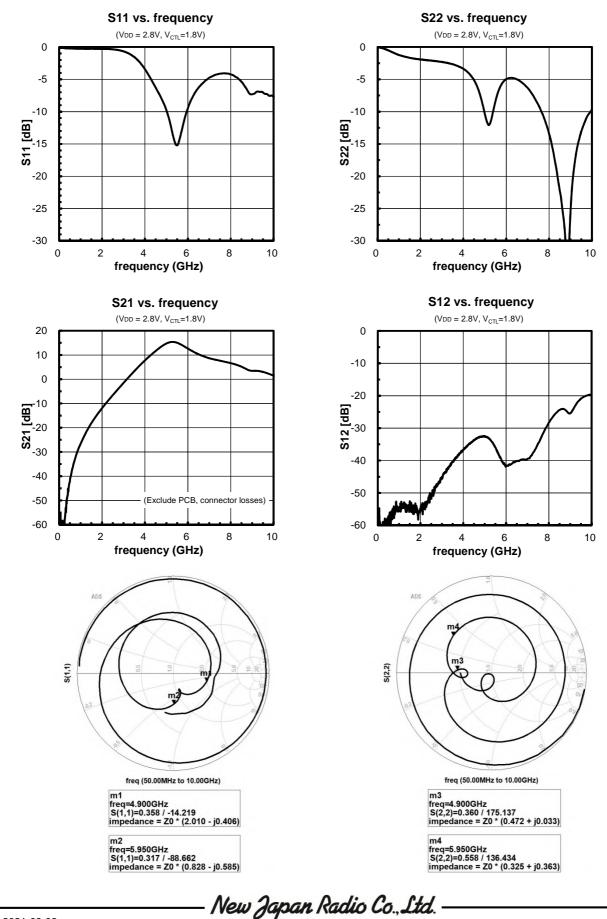


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# ■ ELECTRICAL CHARACTERISTICS (LNA active mode)

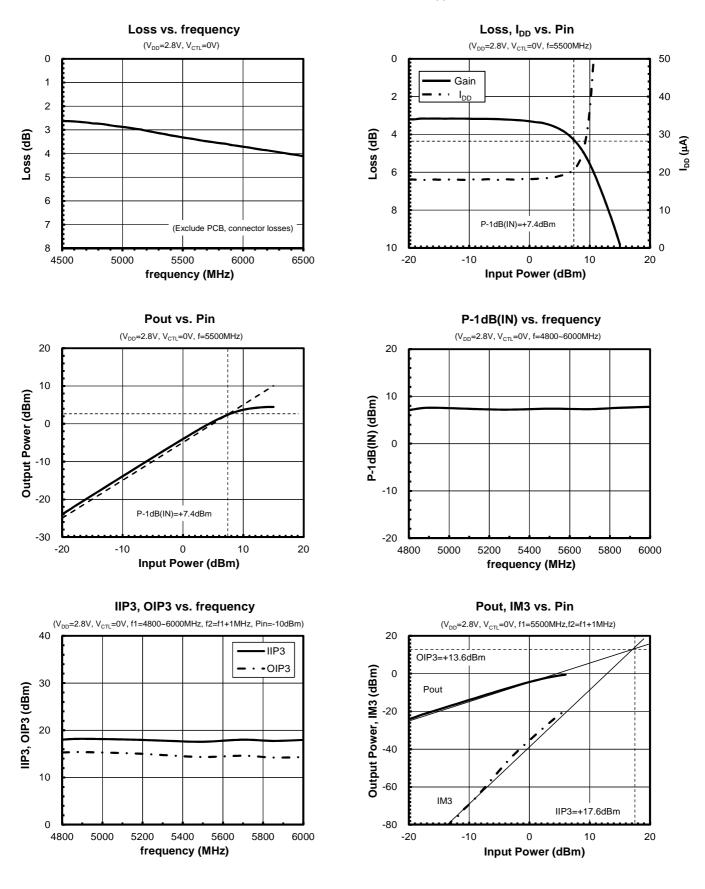
Conditions:  $V_{DD}=2.8V$ ,  $V_{CTL}=1.8V$ ,  $f_{RF}=50MHz$  to 10000MHz,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_I=50\Omega$ , with application circuit





# ■ ELECTRICAL CHARACTERISTICS (Bypass mode)

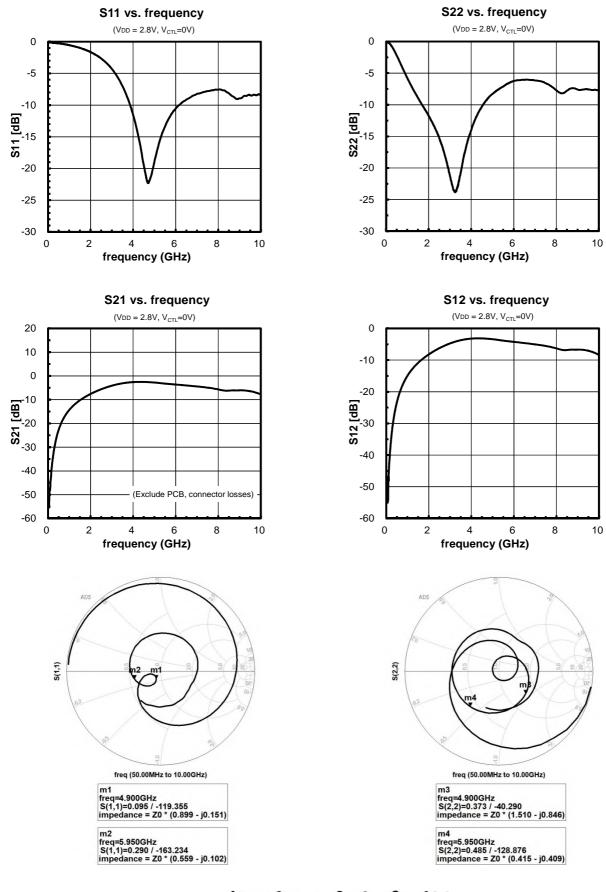
Conditions:  $V_{DD}=2.8V$ ,  $V_{CTL}=0V$ ,  $f_{RF}=5500MHz$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_I=50\Omega$ , with application circuit





#### ■ ELECTRICAL CHARACTERISTICS (Bypass mode)

Conditions: V<sub>DD</sub>=2.8V, V<sub>CTL</sub>=0V, f<sub>RF</sub>=50MHz to 10000MHz, T<sub>a</sub>=+25°C, Z<sub>s</sub>=Z<sub>I</sub>=50Ω, with application circuit

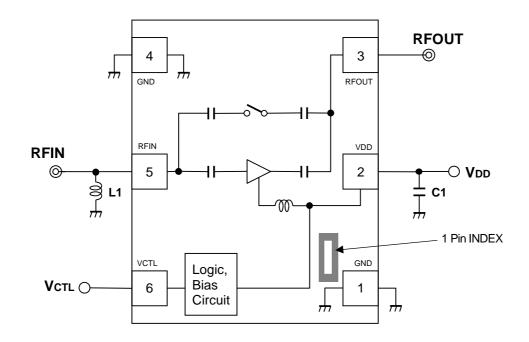


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# ■ APPLICATION CIRCUIT

(Top view)



#### Parts list

| Part ID  | Value     | Notes             |
|----------|-----------|-------------------|
| 14       | L1 1.6nH  | LQP03TN_02 series |
| LI       |           | (MURATA)          |
| <u> </u> | C1 4700pF | GRM03 series      |
| CI       |           | (MURATA)          |

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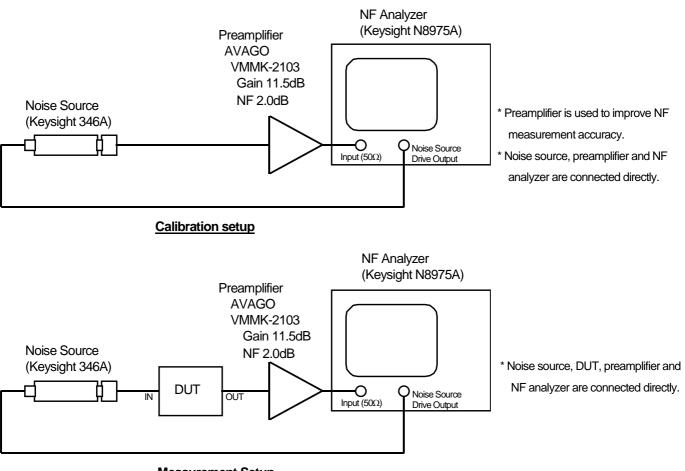
#### ■ NF MEASUREMENT BLOCK DIAGRAM

# Measuring instruments

| NF Analyzer  | : Keysight N8975A |
|--------------|-------------------|
| Noise Source | : Keysight 346A   |

# Setting the NF analyzer

| Measurement mode form |   |
|-----------------------|---|
| Device under test     | : Amplifier   |
| System downconverter  | : off   |
| Mode setup form       |   |
| Sideband              | : LSB   |
| Averages              | : 16  |
| Average mode          | : Point   |
| Bandwidth             | : 4MHz  |
| Loss comp             | : off   |
| Tcold                 | : setting the temperature of noise source (305.15K) |



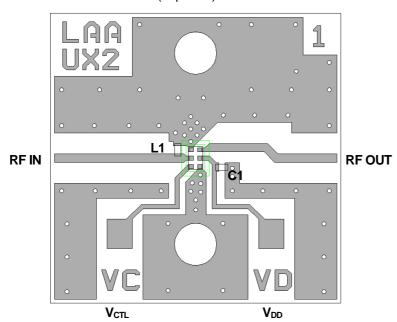
Measurement Setup

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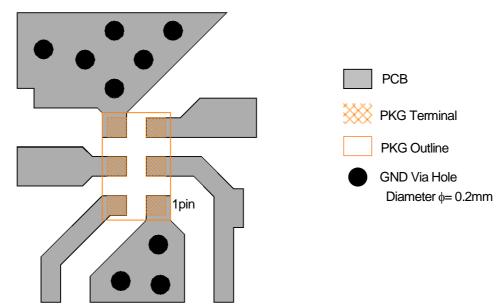
#### EVALUATION BOARD

(Top View)



PCB Information Substrate: FR-4 Thickness: 0.2mm Microstrip line width: 0.4mm (Z<sub>0</sub>=50Ω) Size: 14.0mm x 14.0mm

#### < PCB LAYOUT GUIDELINE>



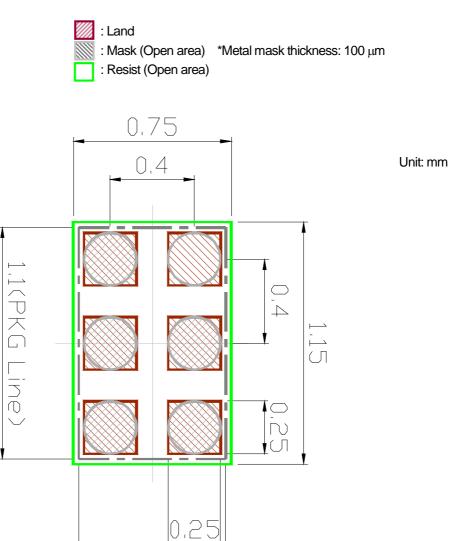
# PRECAUTIONS

- All external parts should be placed as close as possible to the IC.
- For good RF performance, all GND terminals must be connected to PCB ground plane of substrate, and via-holes for GND should be placed near the IC.

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#### ■ RECOMMENDED FOOTPRINT PATTERN (EPFFP6-X2)



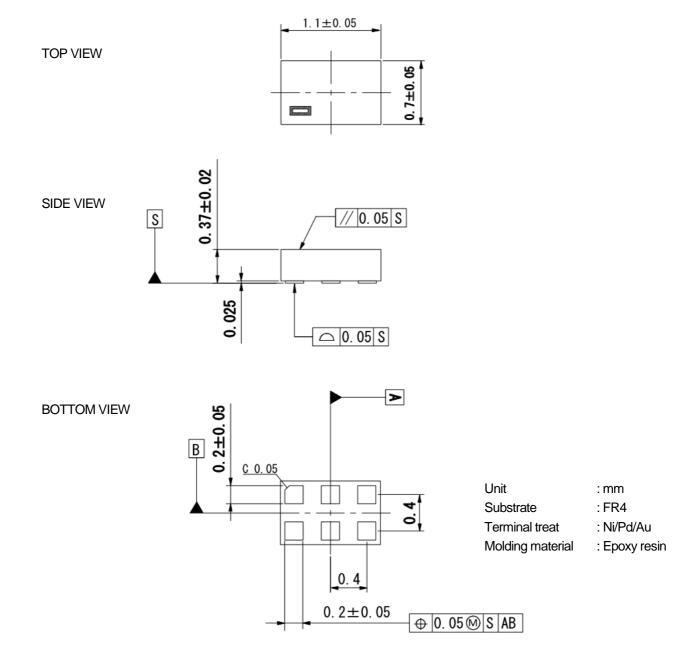
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0.7(PKG Line)



# ■ PACKAGE OUTLINE (EPFFP6-X2)



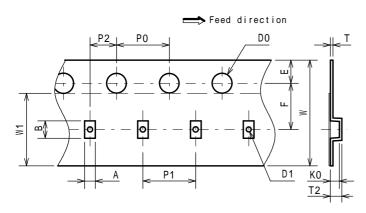
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# NJG1182UX2

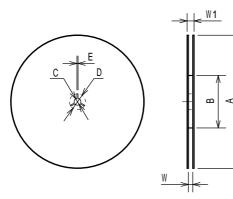
Unit: mm

#### PACKING SPECIFICATION (EPFFP6-X2) TAPING DIMENSIONS



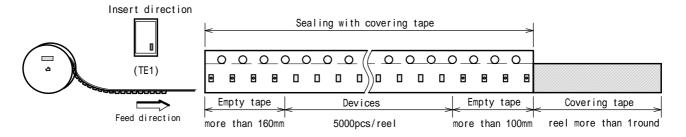
| SYMBOL | DIMENSION           | REMARKS          |
|--------|---------------------|------------------|
| A      | $0.85 \pm 0.03$     | BOTTOM DIMENSION |
| В      | $1.25 \pm 0.03$     | BOTTOM DIMENSION |
| DO     | 1.5 <sup>+0.1</sup> |                  |
| D1     | $0.35 \pm 0.05$     |                  |
| Е      | 1.75±0.1            |                  |
| F      | 3.5±0.05            |                  |
| P0     | 4.0±0.1             |                  |
| P1     | 4.0±0.1             |                  |
| P2     | 2.0±0.05            |                  |
| Т      | $0.2 \pm 0.05$      |                  |
| T2     | 0.75                |                  |
| KO     | $0.45 \pm 0.05$     |                  |
| W      | 8.0 +0.3            |                  |
| W1     | 5.5                 | THICKNESS 0.1max |

**REEL DIMENSIONS** 

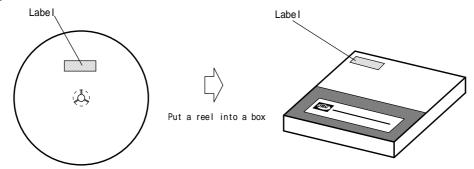


| SYMBOL | DIMENSION                     |
|--------|-------------------------------|
| А      | 180 <sub>-1.5</sub>           |
| В      | 60 <sup>+1</sup> <sub>0</sub> |
| С      | 13±0.2                        |
| D      | 21 ± 0.8                      |
| Е      | 2±0.5                         |
| Ŵ      | 9 <sup>+0.3</sup>             |
| W1     | 11.4±0.1                      |

TAPING STATE



PACKING STATE



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Т

# [CAUTION]

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  - Various Safety Devices

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